

National Semiconductor

LM106/LM306 Voltage Comparator

General Description

The LM106 series are high-speed voltage comparators designed to accurately detect low-level analog signals and drive a digital load. They are equivalent to an LM710, combined with a two input NAND gate and an output buffer. The circuits can drive RTL, DTL or TTL integrated circuits directly. Furthermore, their outputs can switch voltages up to 24V at currents as high as 10 mA.

The devices have short-circuit protection which limits the inrush current when it is used to drive incandescent lamps, in addition to preventing damage from accidental shorts to the positive supply. The speed is equivalent to that of an LM710. However, they are even faster where buffers and additional logic circuitry can be eliminated by the increased flexibility of the LM106 series. They can also be operated from any negative supply voltage between -3V and -12V with little effect on performance.

The LM106 is specified for operation over the -55°C to + 125°C military temperature range. The LM306 is specified for operation over 0°C to +70°C temperature range.

Features

- Improved accuracy
- Fan-out of 10 with DTL or TTL
- Added logic or strobe capability
- Useful as a relay or lamp driver
- Plug-in replacement for the LM710
- 40 ns maximum response time



Schematic and Connection Diagrams

LM106/LM306

Absolute Maximum Ratings If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications. (Note 6)

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Positive Supply Voltage	15V
Negative Supply Voltage	-15V
Output Voltage	24V
Output to Negative Supply Voltage	30V
Differential Input Voltage	±5V
Input Voltage	±7V

Power Dissipation (Note 1)	600 mW	
Output Short Circuit Duration	10 seconds	
Operating Temperature Range LM106 LM306	T _{MIN} T _{MAX} −55°C to +125°C 0°C to +70°C	
Storage Temperature Range	-65°C to +150°C	
Lead Temperature (Soldering, 10 sec.)	300°C	
ESD rating to be determined.		

Electrical Characteristics (Note 2)

Parameter	Conditions		LM106		LM306			Units	
r ai anie lei	Conditions	Min	Ain Typ Max		Min Typ Max				
Input Offset Voltage	(Note 3)		0.5	2.0		1.6	5.0	mV	
Input Offset Current	(Note 3)		0.7	3.0	- ()-	1.8	5.0	μA	
Input Bias Current	(j)		10	20		16	25	μA	
Response Time	$R_{L} = 390\Omega \text{ to } 5V$ $C_{L} = 15 \text{ pF, (Note 4)}$		28	40	÷	28	40	ns	
Saturation Voltage	$\label{eq:VIN} \begin{array}{l} V_{\text{IN}} \leq -5 \text{mV}, I_{\text{OUT}} = 100 \text{mA} \\ V_{\text{IN}} \leq -7 \text{mV}, I_{\text{OUT}} = 100 \text{mA} \end{array}$		1.0	1.5		0.8	2.0	v v	
Output Leakage Current	$\label{eq:VIN} \begin{array}{l} V_{IN} \geq 5 \text{ mV, 8V} \leq V_{OUT} \leq 24 V \\ V_{IN} \geq 7 \text{ mV, 8V} \leq V_{OUT} \leq 24 V \end{array}$		0.02	1.0		0.02	2.0	μΑ μΑ	
THE FOLLOWING SPECIFICATION	S APPLY FOR $T_{MIN} \leq T_A \leq T_{MAX}$	(Note 5)						
Input Offset Voltage	(Note 3)			3.0			6.5	mV	
Average Temperature Coefficient of Input Offset Voltage			3.0	10		5	20	μV/%	
Input Offset Current	T _L ≤ T _A ≤ 25°C, (Note 3) 25°C ≤ T _A ≤ T _H	-10	1.8 0.25	7.0 3.0		2.4	7.5 5.0	μΑ μΑ	
Average Temperature Coefficient of Input Offset Current	25°C ≤ T _A ≤ T _H T _L ≤ T _A ≤ 25°C		5.0 15	25 75		15 24	50 100	nA/% nA/%	
Input Bias Current	T _L ≤ T _A ≤ 25°C 25°C ≤ T _A ≤ T _H			45 20		25	40 25	μΑ μΑ	
Input Voltage Range	-7V ≥ V ⁻ ≥ -12V	±5.0			±5.0			v	
Differential Input Voltage Range		±5.0			±5.0			v	
Saturation Voltage	$V_{IN} \le -5 \text{ mV}$, $I_{OUT} = 50 \text{ mA}$ $V_{IN} \le -8 \text{ mV}$ For LM306			1.0			1.0	v	
Saturation Voltage	$V_{IN} \le -5 \text{ mV}$, $I_{OUT} = 16 \text{ mA}$ $V_{IN} \le -8 \text{ mV}$ For LM306	÷.		0.4			0.4	v	
Positive Output Level	$ \begin{array}{l} V_{IN} \geq 5 \text{ mV}, I_{OUT} = -400 \mu \text{A} \\ V_{IN} \geq 8 \text{ mV For LM306} \end{array} $	2.5		5.5	2.5		5.5	v	
Output Leakage Current	$ \begin{split} &V_{\text{IN}} \geq 5 \text{ mV}, 8V \leq V_{\text{OUT}} \leq 24V \\ &V_{\text{IN}} \geq 8 \text{ mV} \text{ For LM306} \\ &T_{\text{L}} \leq T_{\text{A}} \leq 25^{\circ}\text{C} \\ &25^{\circ}\text{C} < T_{\text{A}} \leq T_{\text{H}} \end{split} $			1.0 100			2.0	μA μA	
Strobe Current	V _{STROBE} = 0.4V		-1.7	-3.2		-1.7	-3.2	 mA	

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Electrical Characteristics (Note 2) (Continued)								
Parameter	Conditions	LM106						
		Min	Тур	Max	Min	Тур	Max	Units
Strobe "ON" Voltage		0.9	1.4		0.9	1.4		V
Strobe "OFF" Voltage	$I_{SINK} \le 16 \text{mA}$		1.4	2.2		1.4	2.2	V
Positive Supply Current	$V_{IN} = -5 \text{ mV}$ $V_{IN} = -8 \text{ mV}$ for LM306		5.5	10		5.5	10	mA
Negative Supply Current			-1.5	-3.6		-1.5	-3.6	mA

Note 1: The maximum junction temperature of LM106 is 150°C, LM306 is 85°C. For operating at elevated temperatures, devices must be derated based on a thermal resistance of 170°C/W, junction to ambient, or 23°C/W, junction to case.

Note 2: These specifications apply for $-3V \ge V^- \ge -12V$, $V^+ = 12V$ and $T_A = 25^{\circ}C$ unless otherwise specified. All currents into device pins are considered positive.

Note 3: The offset voltages and offset currents given are the maximum values required to drive the output down to 0.5V or up to 4.4V (0.5V or up to 4.8V for the LM306). Thus, these parameters actually define an error band and take into account the worst-case effects of voltage gain, specified supply voltage variations, and common mode voltage variations.

Note 4: The response time specified (see definitions) is for a 100 mV input step with 5 mV overdrive.

Note 5: All currents into device plns are considered positive.

Note 6: Refer to RETS106X for LM106 military specifications.

Typical Applications



Fast Response Peak Detector



Relay Driver V⁺⁺ ≤ 24V D1 1N457 K1 INPUTS 3 - LM106 7

TL/H/7756-6

Adjustable Threshold Line Receiver



TL/H/7756-7

LM106/LM306

Typical Performance Characteristics 13.11 **Transfer Function** Transconductance Voltage Gain 10 V+ = +12V -3V 2V" 2-15V 10 - 25°C 18 VOLTAGE GAIN (V/mV) 6 **DUTPUT CURRENT (A)** DUTPUT VOLTAGE (V) 10-T. = 125°C 10-40 - 101 10 V+ = +12V 10--3V 2V" 2-12V 25° 20 10-10 -55°C 10-9 -+ 3 n -03 -2 -3 -4 -0.2 -0.1 0 +0.1 +0.2 +0.3 +0.4 +0.5 +2 +1 0 -1 -6 -75 -50 -26 0 +25 +50 +75 INPUT VOLTAGE (mV) INPUT VOLTAGE (mV) TEMPERATURE (°C) **Saturation Voltage Positive Output Level** Short Circuit Output Current 1.2 V+ +12V V" = -6V 1.1 VIN = -5 mV SATURATION VOLTAGE (V) ¥* - +12¥ - 8 DUTPUT VOLTAGE (V) CURRENT (A) -3V ≥ V" ≥ V,n = -5 mV -121 5 = -400 · 54 mA 0.2 DUTPUT 3 = 16 m/ V+ = +12V 3V≥V->-12V - 0 mA VIN = +5 mV 0 -76 -75 -50 -25 0 +25 +50 +75 +100 +125 0 +25 +50 +75 +100 +125 TEMPERATURE (°C) -75 -50 -25 0 +25 +50 +75 +100 +125 +150 -50 -26 JUNCTION TEMPERATURE (°C) TEMPERATURE (°C) **Response Time for Response Time for Input Current** Various Input Overdrives **Various Input Overdrives** 40 VOLTAGE (mV) | OUTPUT VOLTAGE (V) OUTPUT VOLTAGE (V) V+ = +12V 30 5 V" = -6V 4 20 BIAS 3 3 INPUT CURRENT (JA) 10 z 0 INPUT VOLTAGE (mV) 3 0 100 2 -50 58 OFFSET 1 100 ŧ NPUT 0 28 40 60 80 100 120 25 0 25 50 75 Temperature (°C) 20 40 60 80 100 120 8 100 125 0 -75 -50 -25 TIME (ms) TIME (m) **Positive Supply Current Negative Supply Current Power Consumption** 120 19 ¥* = +12¥ 110 POSITIVE SUPPLY CURRENT (mA) **WEGATIVE SUPPLY CURRENT (mA)** V" = -6V -5 m1 . 100 3 POWER DISSIPATION (mW -55°C 90 TA . 2 70 50 50

+100 +125

i00Ω

-121

0 +25 +50 +75 +100 +125

TL/H/7756-8

TEMPERATURE (°C)

-12

-15

-15\

+15

+12

POSITIVE SUPPLY VOLTAGE (V)

.

+18

a

-1

-6

-1

NEGATIVE SUPPLY VOLTAGE (V)

40

30

-75 -58 -25